

Vishay Semiconductors

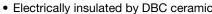
INT-A-PAK Power Modules Ultrafast Diodes, 300 A



INT-A-PAK

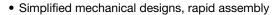
PRODUCT SUMMARY				
I _{F(AV)} at T _C	300 A at 48 °C			
V_{R}	600 V			
t _{rr} (typical)	130 ns			
I _{F(DC)} at T _C	230 A at 100 °C			

FEATURES



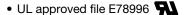


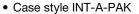






• Large creepage distances







• Designed and qualified for industrial level

RES	A
cally insulated by DBC ceramic	Pb-free
_{PMS} isolating voltage	Pb-free

RoHS COMPLIANT

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Cathode to anode voltage	V_R		600	V	
Continuous forward accurant now los		T _C = 25 °C	435		
Continuous forward current per leg	I _F	T _C = 100 °C	230	А	
Single pulse forward current	I _{FSM}	Limited by junction temperature	TBD		
Maximum power dissipation per leg	P _D	T _C = 25 °C	781	w	
Maximum power dissipation per leg		T _C = 100 °C	313		
Operating junction and storage temperature range	T _J , T _{Stg}		- 40 to 150	°C	
RMS insulation voltage	V _{INS}	50 Hz, circuit to base, all terminals shorted, t = 1 s	3500	V	

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V_{BR}	Ι _R = 500 μΑ	600	-	-	
Forward voltage drop per leg	V _{FM}	I _F = 150 A	-	1.23	1.53	
		I _F = 300 A	-	1.43	1.96	V
		I _F = 150 A, T _J = 125 °C	-	1.11	1.29	
		I _F = 300 A, T _J = 125 °C	-	1.39	1.73	
Maximum reverse leakage current	I _{RM}	T _J = 150 °C, V _R = 600 V	-	-	50	mA

VSKDU300/06PbF

Vishay Semiconductors

INT-A-PAK Power Modules Ultrafast Diodes, 300 A



Document Number: 94549

Revision: 19-May-10

DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
D	t _{rr}	T _J = 25 °C	I _F = 50 A dl/dt = 200 A/μs V _R = 400 V (per leg)	-	130	165	ns
Reverse recovery time		T _J = 125 °C		-	195	260	
Peak recovery current		T _J = 25 °C		-	11	18	А
reak recovery current	I _{rr}	T _J = 125 °C		-	20	30	
Povorco rocovení oborco	0	T _J = 25 °C		=	670	1485	nC
Reverse recovery charge Q _{rr}	T _J = 125 °C		-	1800	3900	110	
Peak rate of recovery current	dI _{(rec)M} /dt	T _J = 125 °C		-	-	400	A/μs
Outlineau fautamenta	_	I _F = 50 A, T _J = 25 °C, dl.	$/dt = 400 \text{ A/}\mu\text{s}, V_{R} = 200 \text{ V}$	-	0.2	-	
Softness factor per leg	oftness factor per leg		$I_F = 50 \text{ A}, T_J = 125 ^{\circ}\text{C}, dI/dt = 400 \text{A/}\mu\text{s}, V_R = 200 \text{V}$		0.22	-	

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction operating an storage temperature range	T _J , T _{Stg}		- 40 to 150	°C	
Maximum thermal resistance, junction to case per leg	nce, R _{thJC} DC operation		0.16	14.004	
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	0.05	K/W	
Mounting to heat	sink	A mounting compound is recommended and the	4+- 0	Nima	
torque ± 10 % bus	sbar	torque should be rechecked after a period of 3 hours to allow the spread of the compound.	4 to 6	Nm	
Approximate weight			200	g	
Approximate weight			7.1	oz.	
Case style			INT-A	-PAK	



INT-A-PAK Power Modules Ultrafast Diodes, 300 A

Vishay Semiconductors

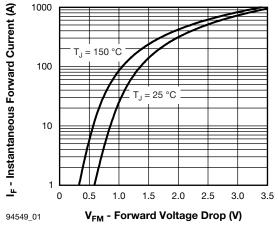


Fig. 1 - Maximum Forward Voltage Drop Characteristics

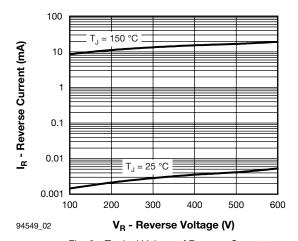


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

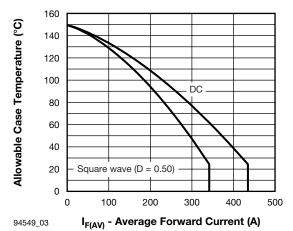


Fig. 3 - Maximum Allowable Case Temperature vs. Average Forward Current

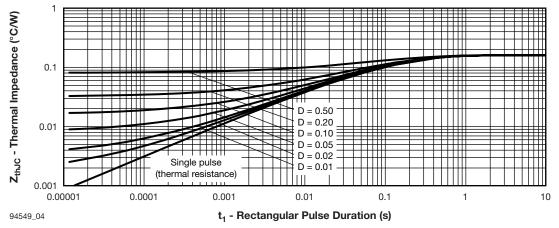


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

Vishay Semiconductors

INT-A-PAK Power Modules Ultrafast Diodes, 300 A



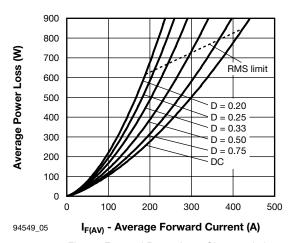


Fig. 5 - Forward Power Loss Characteristics

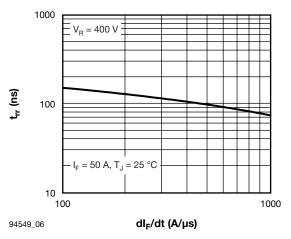


Fig. 6 - Typical Reverse Recovery Time vs. dl_F/dt (Per Leg)

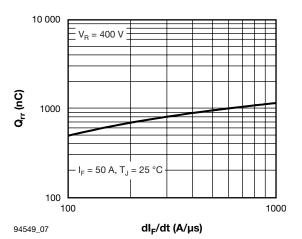


Fig. 7 - Typical Reverse Recovery Charge vs. dl_F/dt (Per Leg)

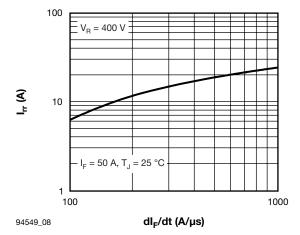


Fig. 8 - Typical Reverse Recovery Current vs. dl_F/dt (Per Leg)



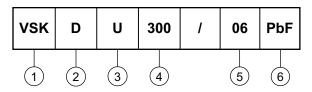


INT-A-PAK Power Modules Ultrafast Diodes, 300 A

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Module type

2 - Circuit configuration:

D = Doubler, 2 diodes in series

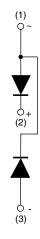
3 - U = Ultrafast diode

Current rating (300 = 300 A)

- Voltage rating (06 = 600 V)

6 - PbF = Lead (Pb)-free

CIRCUIT CONFIGURATION



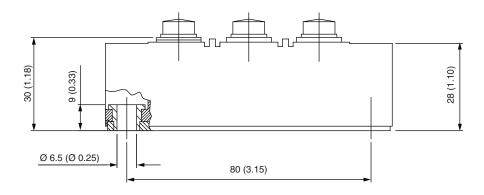
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95254			

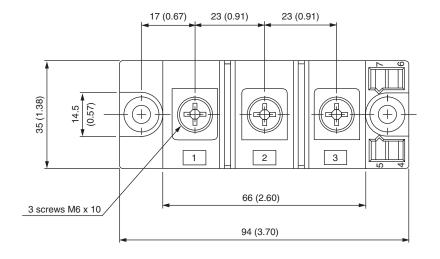


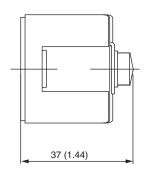
Vishay Semiconductors

INT-A-PAK DBC

DIMENSIONS in millimeters (inches)











Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Revision: 11-Mar-11